**FCCM’20 rebuttal**

**review 2**

a.The "Put it All Together" section in V needs more explanation.  Is it 50 nseconds or roughly 50 cycles?  The latency in table IV is given in cycles, with latency being significantly higher.  Or does this 50ns mean something else?

*The “50ns” means that the memory access latency on HBM is higher than that on DDR4 by about 50 nano second under the same category like page hit. We will update the related sentence in our paper.*

b. Why do "stable latency numbers" demonstrate that your benchmark is efficient?   Latency numbers could be stable with an inefficient benchmark.

*Our benchmarking framework immediately issues the second memory transaction after the read data of the first memory read transaction is returned. Therefore, our framework is able to determine the accurate latency numbers of three memory access categories: page miss, page closed and page hit. From Figure 5, we observe that the latency numbers are stable for memory read transactions under the same category, e.g., page hit, on DDR4 or HBM. To this end, we claim that our benchmarking framework is efficient. We would like to update the sentence to “Second, the latency number is accurate, demonstrating the efficiency of our FPGA-based benchmarking framework.”*

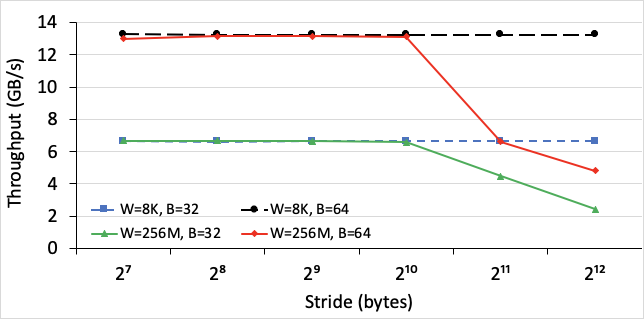
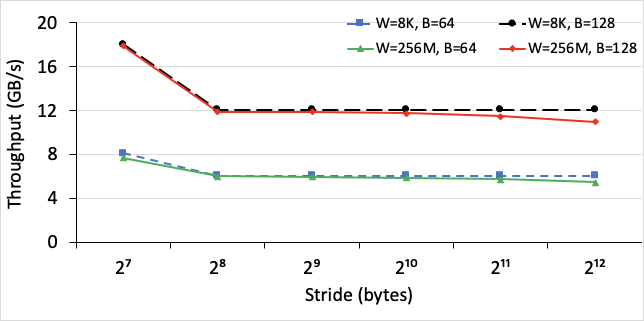
*To our knowledge, there is no related benchmarking framework that is used to analyze memory latency numbers on FPGAs.*

**review 4**

1 Section V.E: what is the meaning of the stride when S >= W? Applying (1) directly (which is still the only reasonable explanation I can come up with) would mean that the modules keep reading the same burst of data, which is equivalent to having S = 0. If this was the case, then it is not a surprise that the bandwidth remains stable at its the maximum value, but then the comparison with W=256M becomes apples-and-oranges when S>8K as you are comparing with S=0 in the W=8K case. For the same reason, I would disagree with identifying small Ws with high access locality which would "relieve the negative effect of large stride S" as the actual stride would be zero. I would argue that any low W/S ratio could be interpreted as high access locality as only a W/S different bursts would be read over and over, and indeed an on-chip cache would improve the bandwidth of those cases as well as long as B is small enough.

*We agree that the case“S >= W”is equivalent to the case“S=0”. Thanks for your pointing out. We will remove the cases (S>=W) in Figure 7. However, even when S is 0 (each memory transaction accesses the same memory address), each memory transaction still goes to DDR chips, not on-chip cache，in the context of HBM/DDR4 memory controllers on our tested FPGA board. Essentially, high access locality potentially leads to a page hit for each memory transaction, while low access locality might lead to a page hit, a page closed or a page miss for a memory transaction. Obviously, page hit (in terms of small W) leads to high memory bandwidth while page closed and page miss (in terms of large W) lead to low memory bandwidth. When W is small, the entire working set can fit in the active banks, meaning that a large S (S < W) still leads to a page hit for each memory transaction. This is the reason why claim that “*relieve the negative effect of large stride S*”.*

*We will add this point in the camera-ready version.*

b.Section V.F: are total bandwidth trends vs B, S, and address mapping policy similar as those for single channel (simply scaled up by a constant factor) or are there more phenomena involved? I'm quite sure there are no surprises from the DDR4 as the two channels are likely completely independent from each other, but the HBM switches that are shared among multiple input channels could, in principle, have an impact on the multi-channel performance.

*We use the case (B=64,S=64, default address mapping policy), each AXI channel accesses its local HBM channel. Each AXI channel accesses its local HBM channel, there is no inference among 32 AXI channels. We add the concrete throughput number for each AXI channel that accesses its local HBM channel:*

*13.2469*

*13.2434*

*13.2423*

*13.2392*

*13.2509*

*13.2495*

*13.2418*

*13.2427*

*13.2381*

*13.2383*

*13.2428*

*13.2436*

*13.2452*

*13.2406*

*13.2447*

*13.2406*

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*13.2395*

*13.2411*

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*13.2519*

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*13.2472*

*13.2428*

*13.2461*

*13.2449*

*The total throughput: 423.8232GB/s.*

*We observe that each AXI channel approximately has the same throughput, so we estimate the total throughput by simply scaling up the throughput of the channel 0 by 32. We will add this point in the camera-ready version.*

**We will submit the following sentences to the system.**

Thanks for the chance to answer clarifying questions raised by the reviewers. We really appreciate your efforts.

For Reviewer 2:

1, *The “50ns” means that the memory access latency on HBM is higher than that on DDR4 by about 50 nano second under the same category like page hit. We will update the related sentence in our paper.*

2, *Our benchmarking framework immediately issues the second memory transaction after the read data of the first memory read transaction is returned. Therefore, our framework is able to determine the accurate latency numbers of three memory access categories: page miss, page closed and page hit. From Figure 5, we observe that the latency numbers are stable for memory read transactions under the same category, e.g., page hit, on DDR4 or HBM. To this end, we claim that our benchmarking framework is efficient. We would like to update the sentence to “Second, the latency number is accurate, demonstrating the efficiency of our FPGA-based benchmarking framework.”*

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